

# **Automation of the baking of the positron/positronium conversion target at AĒgIS**

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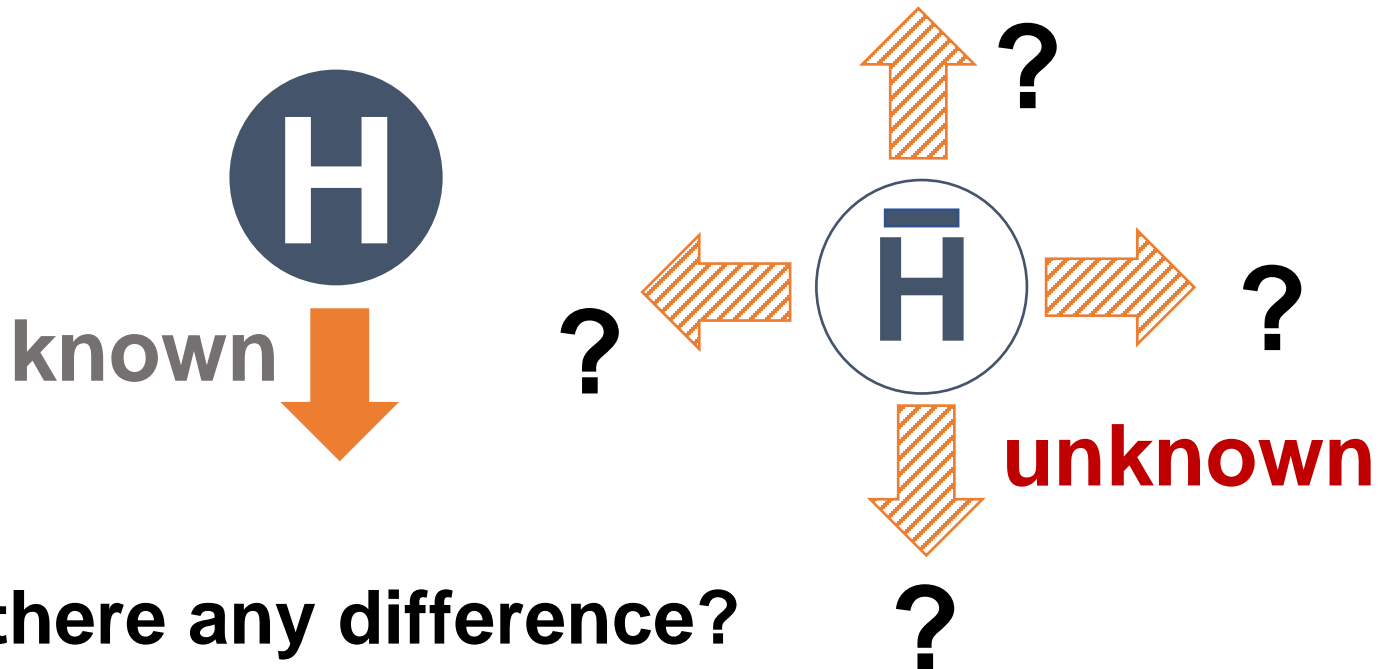
**On behalf of the AĒgIS collaboration**



# AEgIS experiment

## ◆ What we want to know

Gravitational acceleration of anti-matter

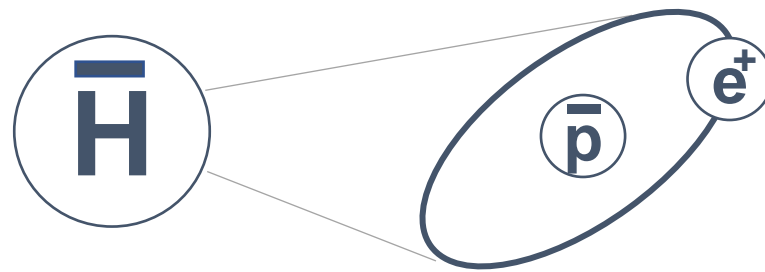


# AEgIS experiment

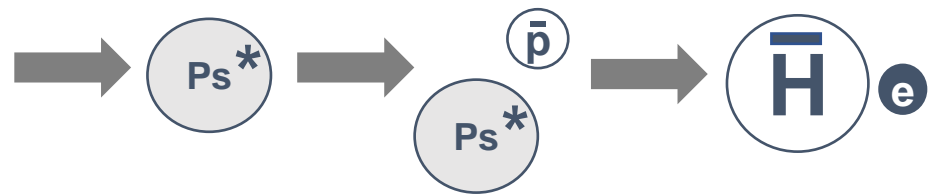
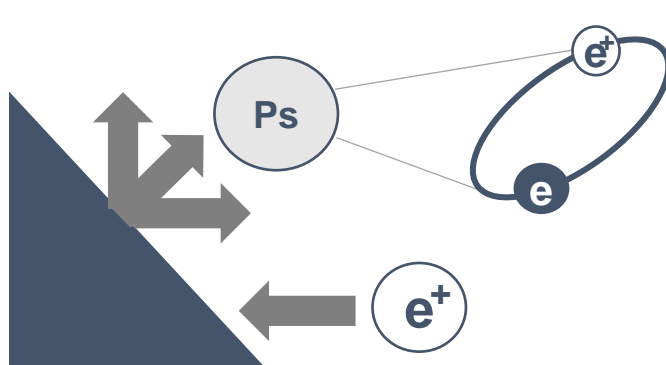
## ◆ What we use

Anti-hydrogen atom

- Pure antimatter
- Neutral charge
- Long life time

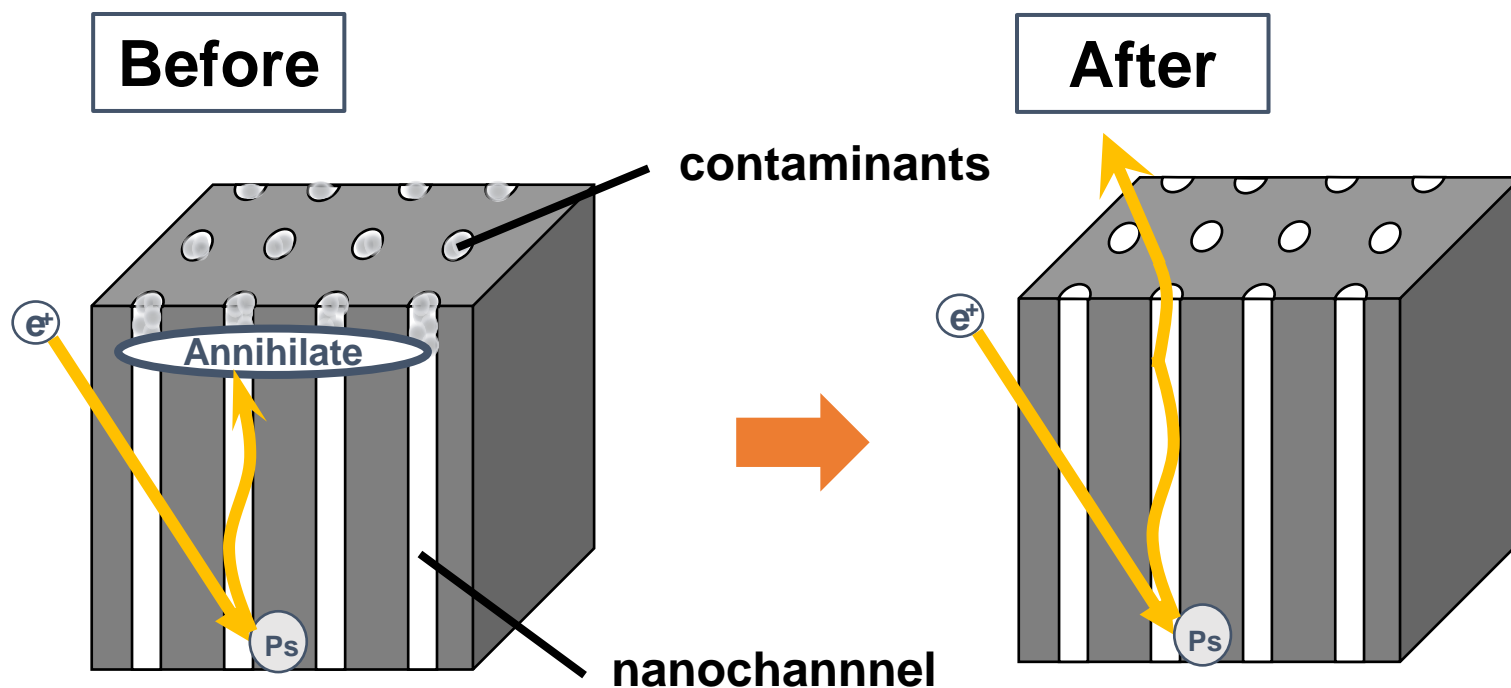


## ◆ How to make



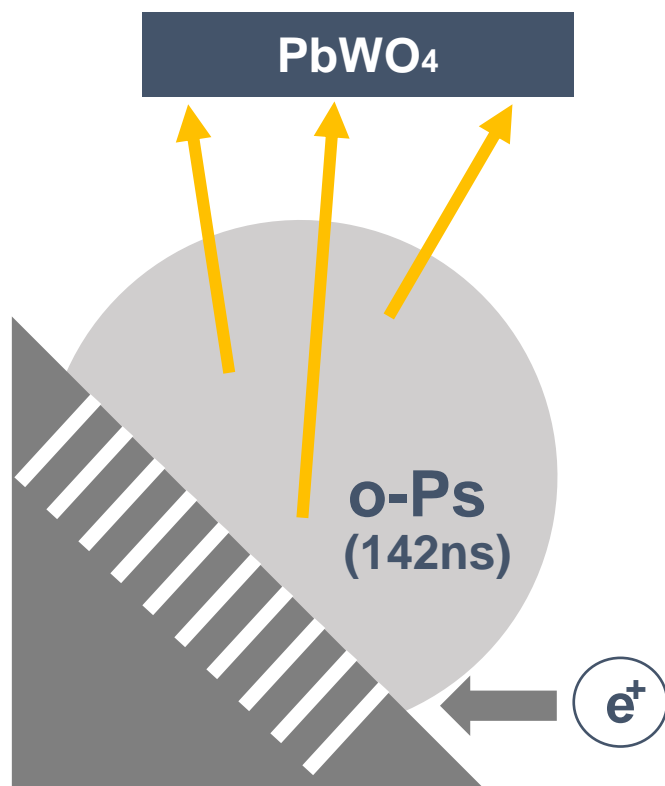
# Target Baking

## ◆ Why do we have to bake



# Target baking

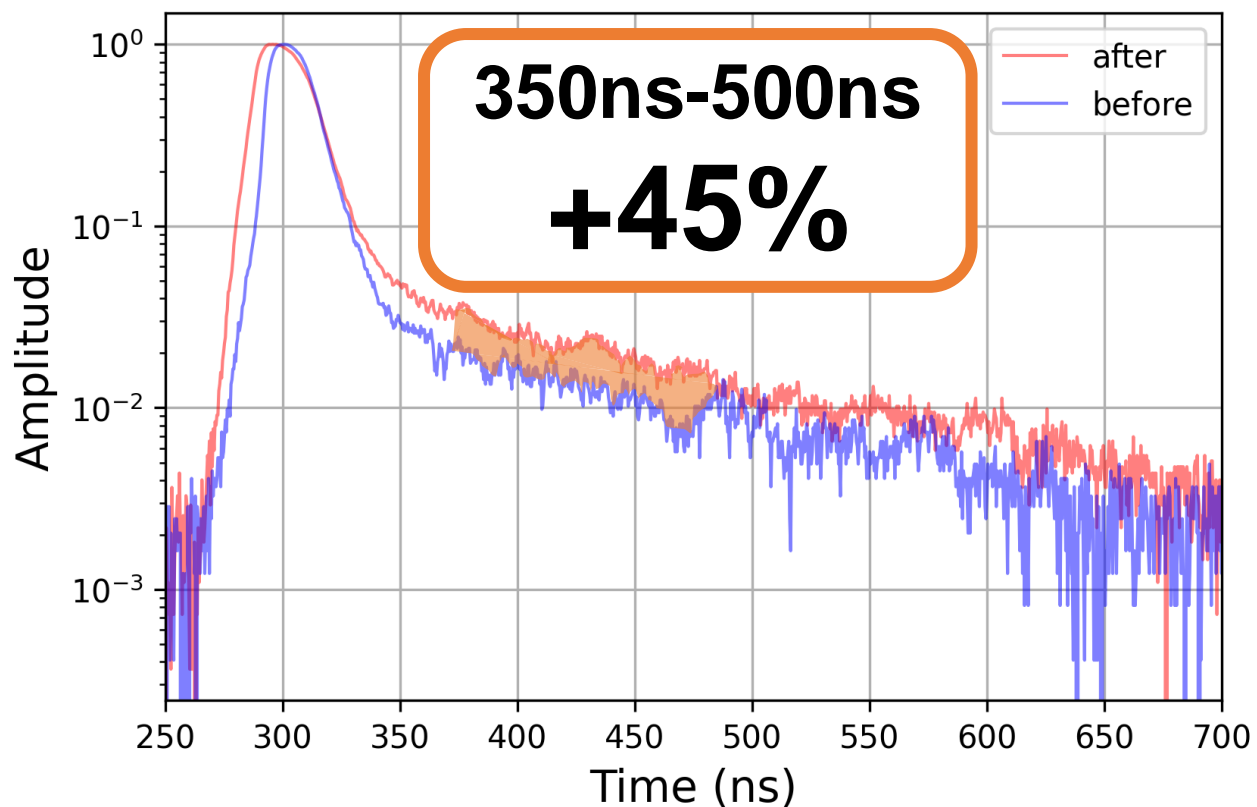
## ◆ Detect produced Positronium



- Detect  $\gamma$ -ray from annihilation
- Compare before/after baking
- Note:  $\gamma$ -ray emitted from ALL annihilation

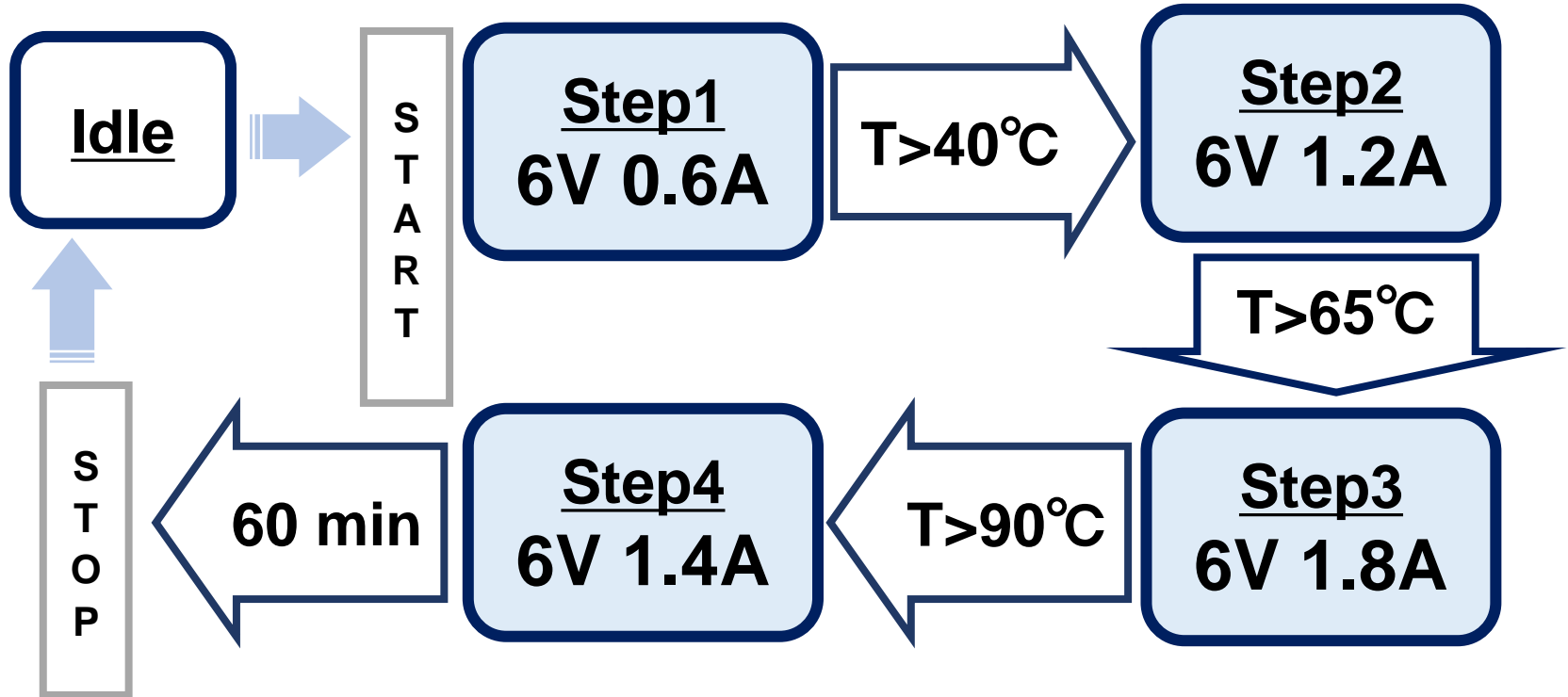
# Target Baking

## ◆ comparison



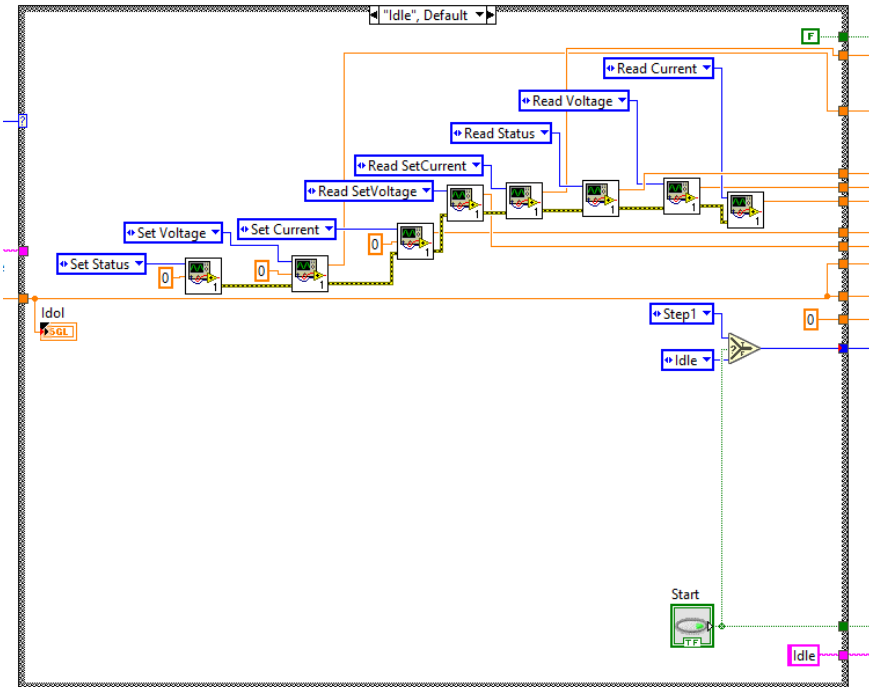
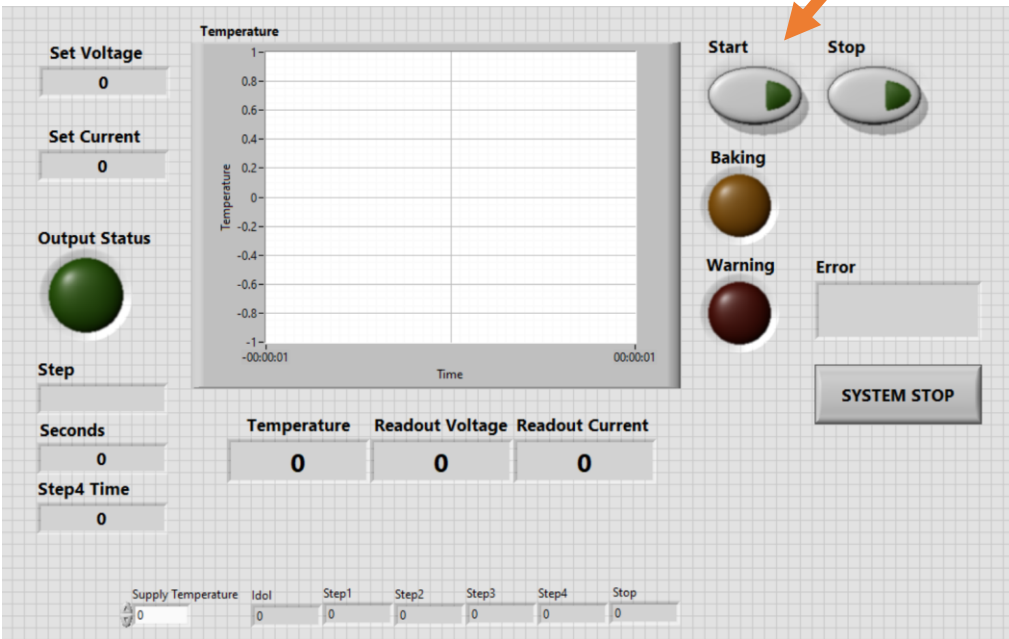
# Baking system

## ◆ Recipe



# Baking system

## ◆ LabVIEW Program





# Reference

- S Mariazzi et al., “High-yield thermalized positronium at room temperature emitted by morphologically tuned nanochanneled silicon targets”, *J. Phys. B: At. Mol. Opt. Phys.*, **54**, 085004 (2021)
- Amsler, C., Antonello, M., Belov, A. et al., “Pulsed production of antihydrogen”, *Commun Phys*, **4**, 19 (2021)
- Adam Deller & David Cassidy, “SSPALS:A tool for studying positronium”, *Nucl. Instrum. Methods A*, **922**, pp. 91-97 (2019)
- M. K. Oberthaler, S. Bernet, E. M. Rasel, J. Schmiedmayer, and A. Zeilinger, “Inertial sensing with classical atomic beams”, *Phys. Rev. A*, **54**(4):31653176, (1996)
- Benjamin Rienäcker, “Creation and manipulation of positronium for efficient antihydrogen production at AEGIS”, Ph.D thesis (2021)

# Acknowledgements

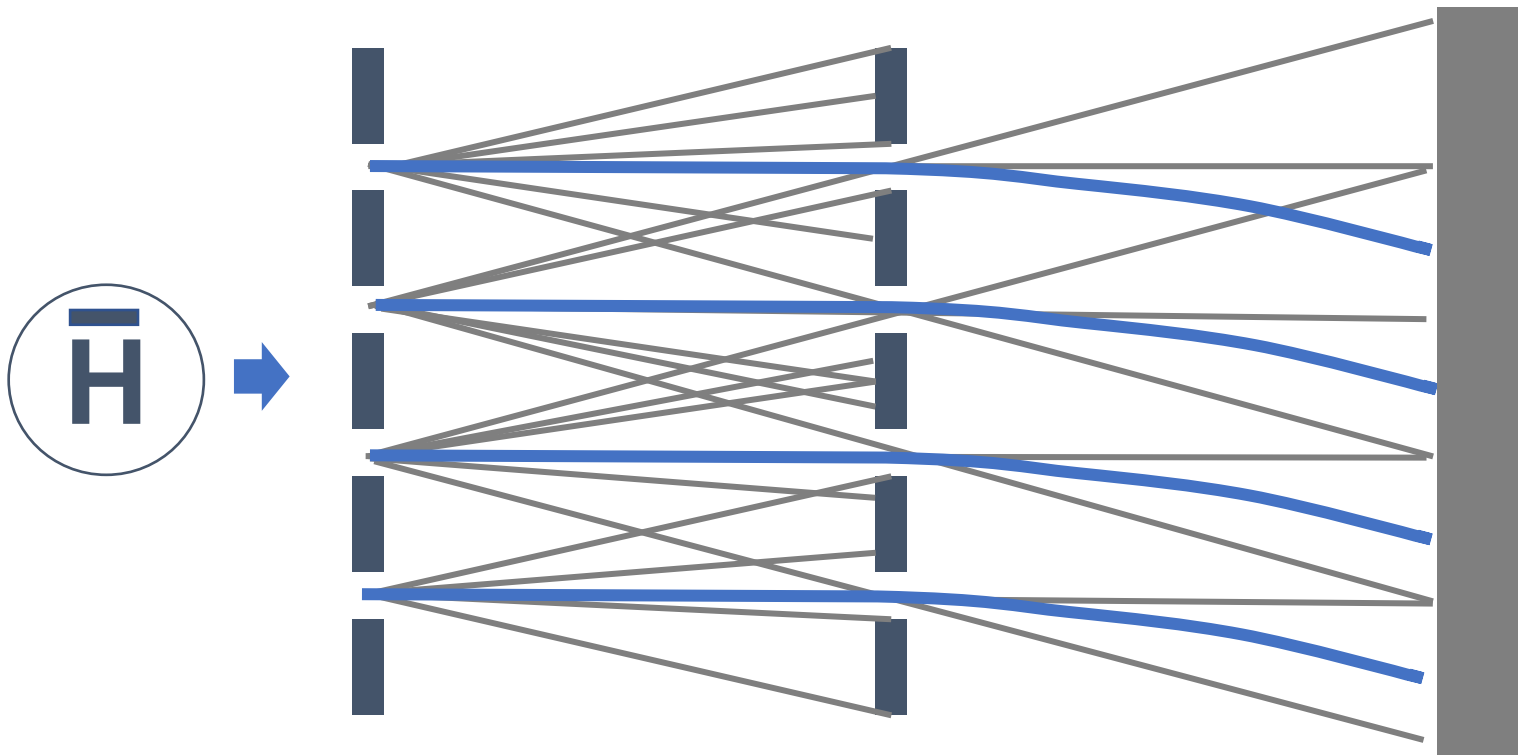
**I am grateful to Dr. Benjamin Rienäcker for useful discussions.**

**I would like to thank the members of AEgIS collaboration.**

**Thank you for listening**

**Back Up**

# Moire Spectrometer



# Laser make lifetime longer

$$\frac{1}{\tau} = \frac{E_{Ps}}{\hbar} \cdot \frac{\alpha^3}{n^3} \cdot \left[ 1 - \frac{\alpha}{\pi} \left( 5 - \frac{\pi^2}{4} \right) - 2\alpha^2 \ln \alpha + 5.1243 \left( \frac{\alpha}{\pi} \right)^2 + \dots \right]$$

**Adding the laser**



**Ps excited**

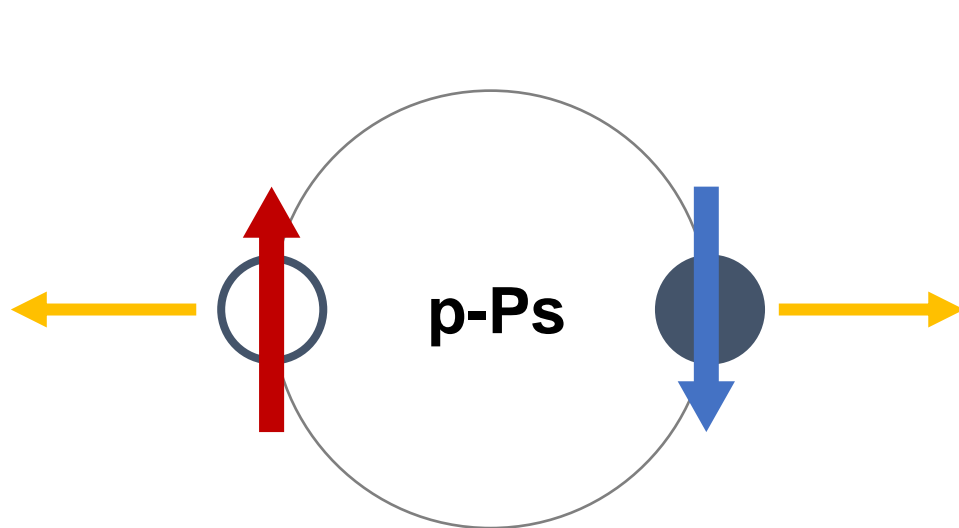


**Diameter bigger**

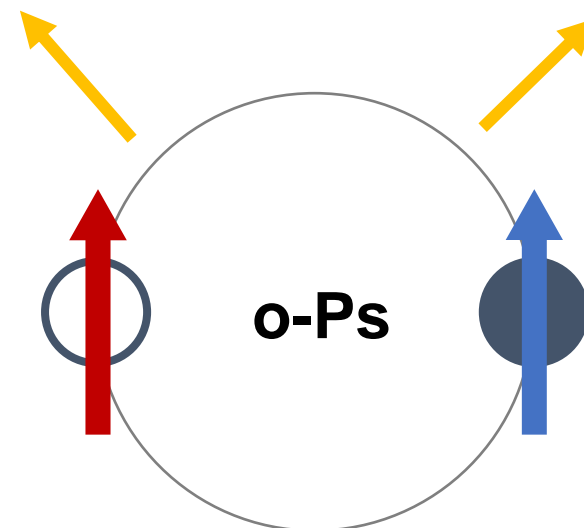


**Probability of encounter decreased**

# Positronium



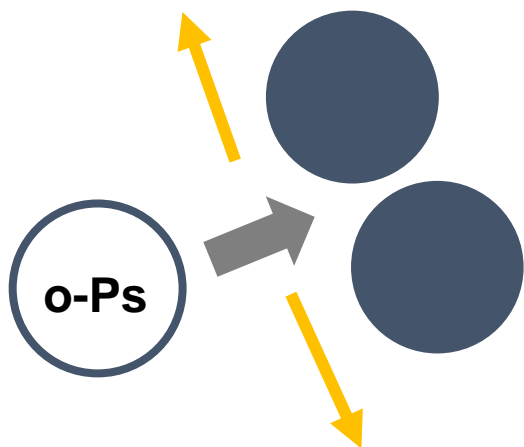
- $S=0$
- even  $\gamma$
- 125 ps



- $S=1$
- odd  $\gamma$
- 142 ns

# Annihilation in material

- **Pick-off**



1. o-Ps touches material surface
2. o-Ps collides with atoms
3. Annihilate
4. Emit  $2\gamma$  (o-Ps finds opposite spin electron w/o binding)

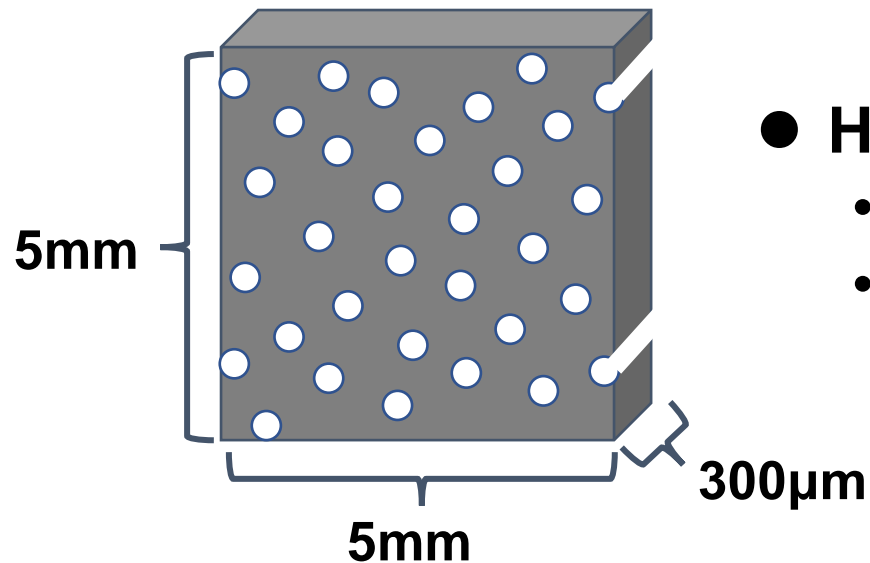
- **Spin flip**

1. o-Ps changes into p-Ps (leptons remain bound)
2. Annihilate with p-Ps lifetime



# Target

- Silicon wafer – SiO<sub>2</sub> layer on channel surface



- Hole - nanochannel
  - $r = 20\text{nm}$
  - depth =  $1\mu\text{m}$